

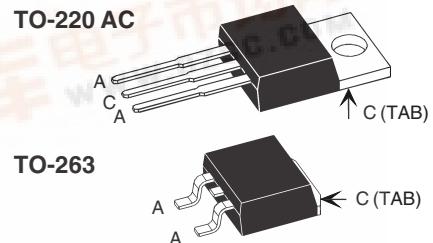
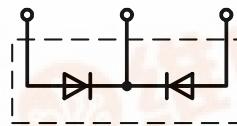


**DSEC 29-02A  
DSEC 29-02AS**

## HiPerFRED™ Epitaxial Diode with common cathode and soft recovery

**I<sub>FAV</sub> = 2x15 A  
V<sub>RRM</sub> = 200 V  
t<sub>rr</sub> = 25 ns**

V <sub>RSM</sub>	V <sub>RRM</sub>	Type
V	V	
200	200	DSEC 29-02A
200	200	DSEC 29-02AS



A = Anode, C = Cathode, TAB = Cathode

Symbol	Conditions	Maximum Ratings		
I <sub>FRMS</sub>		35	A	
I <sub>FAVM</sub>	T <sub>C</sub> = 150°C; rectangular, d = 0.5	15	A	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t <sub>p</sub> = 10 ms (50 Hz), sine	140	A	
E <sub>AS</sub>	T <sub>VJ</sub> = 25°C; non-repetitive I <sub>AS</sub> = 2.5 A; L = 180 µH	0.8	mJ	
I <sub>AR</sub>	V <sub>A</sub> = 1.5·V <sub>R</sub> typ.; f = 10 kHz; repetitive	0.3	A	
T <sub>VJ</sub>		-55...+175	°C	
T <sub>VJM</sub>		175	°C	
T <sub>stg</sub>		-55...+150	°C	
P <sub>tot</sub>	T <sub>C</sub> = 25°C	95	W	
M <sub>d</sub>	mounting torque	0.45...0.55 4...5	Nm lb.in.	
Weight	typical	2 / 4	g	

Symbol	Conditions	Characteristic Values		
		typ.	max.	
I <sub>R</sub> ①	T <sub>VJ</sub> = 25°C; V <sub>R</sub> = V <sub>RRM</sub> T <sub>VJ</sub> = 150°C; V <sub>R</sub> = V <sub>RRM</sub>	100 0.5	µA mA	
V <sub>F</sub> ②	I <sub>F</sub> = 15 A; T <sub>VJ</sub> = 150°C T <sub>VJ</sub> = 25°C	0.86 1.06	V V	
R <sub>thJC</sub> R <sub>thCH</sub>		0.5	1.6 K/W K/W	
t <sub>rr</sub>	I <sub>F</sub> = 1 A; -di/dt = 100 A/µs; V <sub>R</sub> = 30 V; T <sub>VJ</sub> = 25°C	25	ns	
I <sub>RM</sub>	V <sub>R</sub> = 100 V; I <sub>F</sub> = 25 A; -di <sub>F</sub> /dt = 100 A/µs T <sub>VJ</sub> = 100°C	3.5	4.4	A

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %  
② Pulse Width = 300 µs, Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified.

### Advantages

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I<sub>RM</sub> reduces:
  - Power dissipation within the diode
  - Turn-onloss in the commuting switch

Dimensions see Outlines.pdf

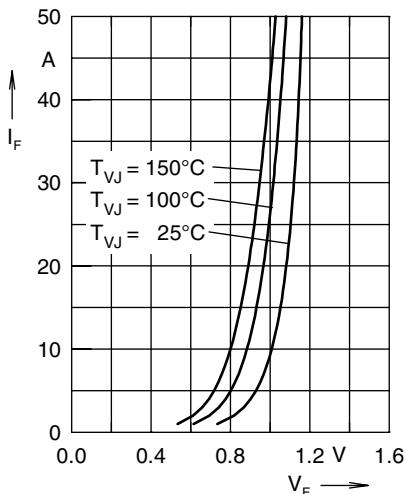


Fig. 1 Forward current  $I_F$  versus  $V_F$

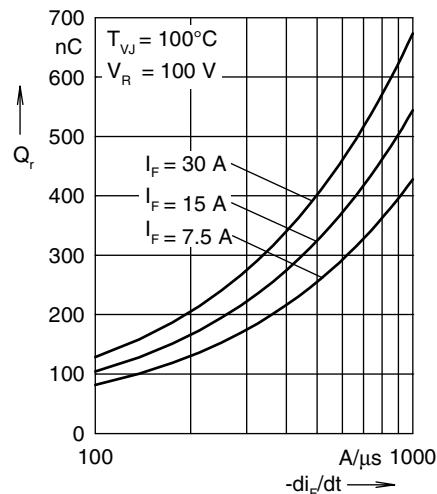


Fig. 2 Typ. reverse recovery charge  $Q_r$

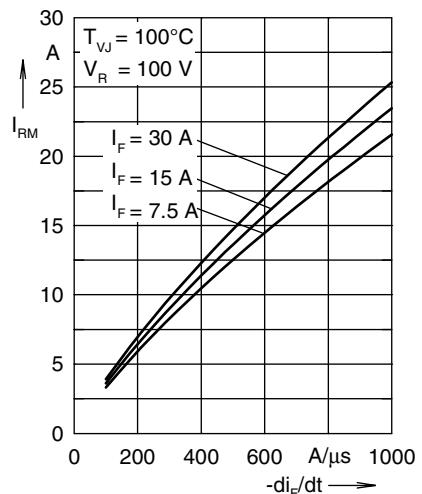


Fig. 3 Typ. peak reverse current  $I_{RM}$

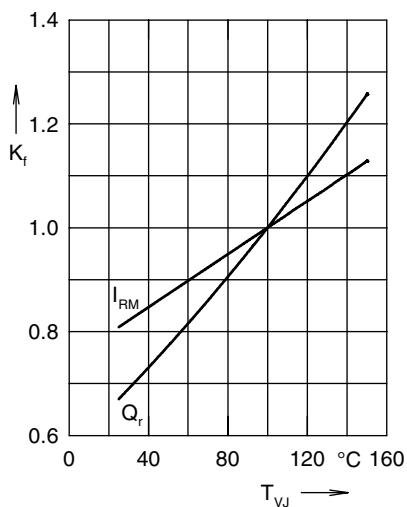


Fig. 4 Typ. dynamic parameters  $Q_r$ ,  $I_{RM}$

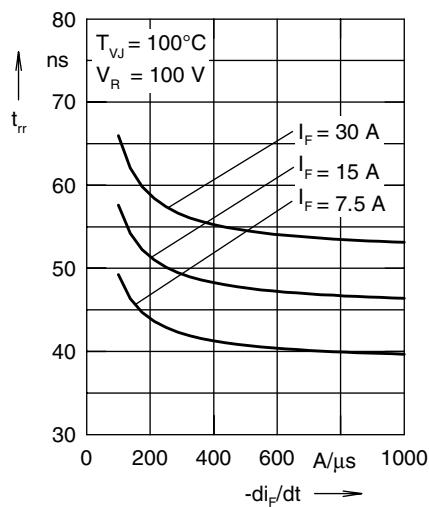


Fig. 5 Typ. recovery time  $t_{rr}$  versus  $-di_F/dt$

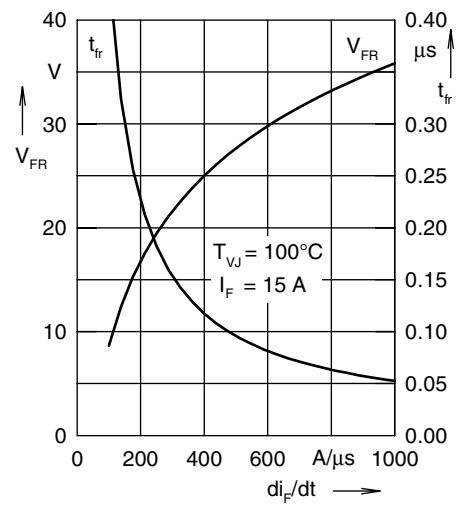


Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{rr}$

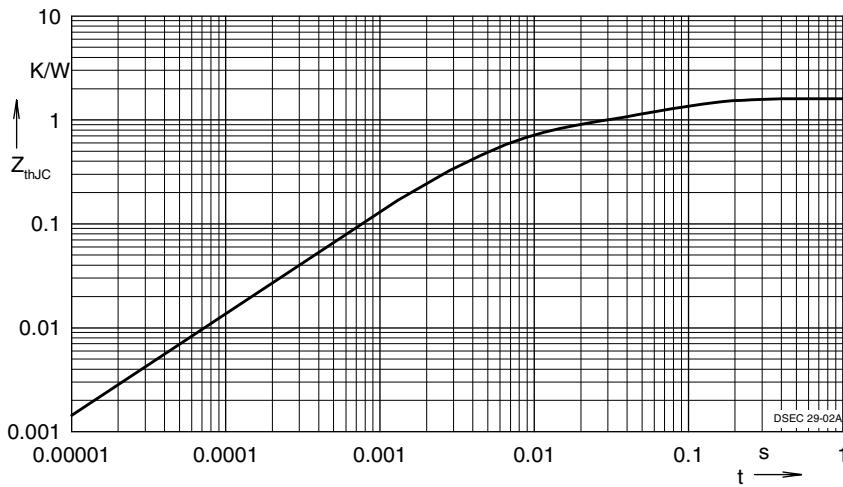


Fig. 7 Transient thermal resistance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.851	0.0052
2	0.328	0.0003
4	0.421	0.0409